

# OSRAM PLPM7 455QA\_LL

## Datasheet

Published by ams-OSRAM AG  
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VEGALAS™ Power

# PLPM7 455QA\_LL

Blue emitting high power multi-die Edge Emitting Laser including beam collimation for all kind of highest power application requiring phosphor conversion or direct emitting blue laser light emission



## Applications

- Entertainment
- Outdoor & Industrial Lighting
- Projection & Display

## Features

- Package: Hermetic Multi Laser Die Top Emitter Package
- Chip Technology: Multimode EEL
- Typical emission wavelength: 455 nm
- Typical optical power: 42 W
- Typical wall plug efficiency of 45 %
- Collimated beam output
- NTC & Connector

## Ordering Information

Type	Peak output power typ. $P_{opt}$	Ordering Code
PLPM7 455QA_LL	42 W	Q65115A1126

## Maximum Ratings

Parameter	Symbol	Values	
Operating temperature <sup>1)</sup>	$T_{op}$	min.	0 °C
		max.	70 °C
Storage temperature	$T_{stg}$	min.	-40 °C
		max.	85 °C
Junction temperature	$T_j$	max.	135 °C
Forward current	$I_F$	max.	3.5 A
Reverse current	$I_R$	max.	85 mA
Reverse voltage for Zener diode at condition 5mA/25°C and no irradiation	$V_R$	max.	15.5 V

Operation outside these conditions may damage the device. Operation at the maximum ratings influences lifetime.

Addendum to above parameter:

\* Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LASER.

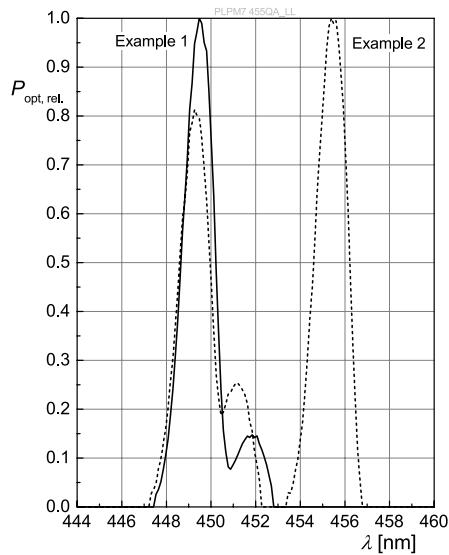
## Characteristics

 $I_F = 3.0 \text{ A}$ ;  $T_{op} = 25^\circ\text{C}$ 

Parameter	Symbol	Values	
Dominant wavelength <sup>2)</sup>	$\lambda_{\text{dom}}$	min.	449 nm
		typ.	455 nm
		max.	461 nm
Optical output power <sup>3)</sup>	$P_{\text{opt}}$	min.	38 W
		typ.	42 W
Beam divergence ( $1/e^2$ ) parallel to pn-junction	$\Theta_{\parallel}$	min.	0 °
		typ.	0.8 °
		max.	1.6 °
Beam divergence ( $1/e^2$ ) perpendicular to pn-junction	$\Theta_{\perp}$	min.	-1.5 °
		typ.	0 °
		max.	1.5 °
Beam pointing tilt angle <sup>4)</sup> $\Delta\theta = \sqrt{(\Delta\theta_{\parallel})^2 + (\Delta\theta_{\perp})^2}$	$\Delta\theta$	max.	1.2 °
Total conversion efficiency	$\eta_{\text{tot}}$	min.	41 %
		typ.	45 %
Slope efficiency	$\eta$	typ.	16.2 W / A
Threshold current	$I_{\text{th}}$	min.	0.24 A
		max.	0.44 A
Forward voltage <sup>5)</sup>	$V_F$	typ.	31 V
		max.	36 V
Forward voltage <sup>5)</sup> for Zener diode at condition 20mA/25°C and no irradiation	$V_F$	min.	0.75 V
		max.	1.20 V
TE polarization (Preliminary value)	$P_{\text{TE}}$	typ.	70:1
Thermal resistance junction board (Board = NTC)	$R_{\text{thJB real}}$	typ.	0.9 K / W

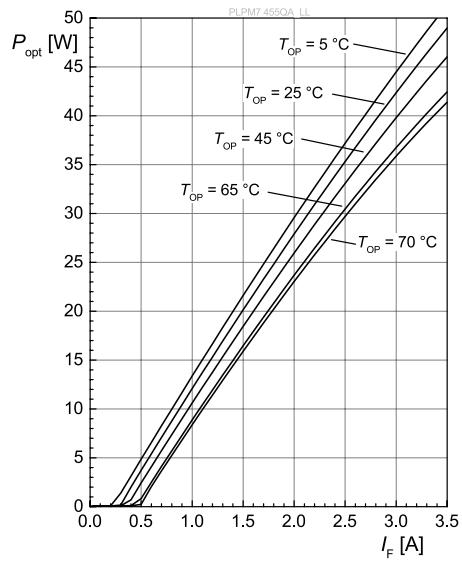
## Relative Spectral Emission <sup>6), 7)</sup>

$$P_{\text{opt}} = f(\lambda); I_F = 3.0 \text{ A}; T_{\text{op}} = 25 \text{ }^{\circ}\text{C}$$



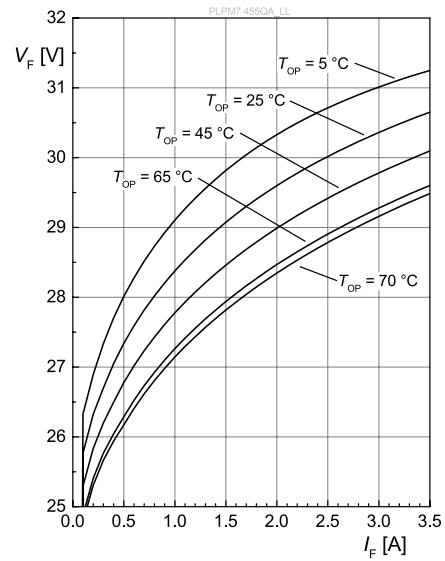
## Optical Output Power <sup>6), 7)</sup>

$$P_{\text{opt}} = f(I_F)$$



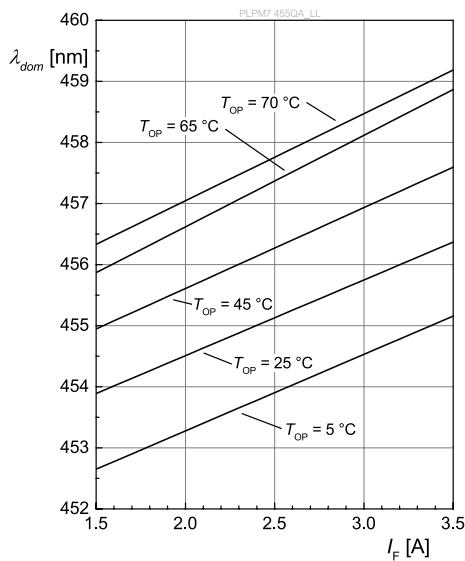
## Operating Voltage <sup>6), 7)</sup>

$$V_F = f(I_F)$$



**Dominant Wavelength** <sup>6), 7)</sup>

$$\lambda_{\text{dom}} = f(I_F)$$

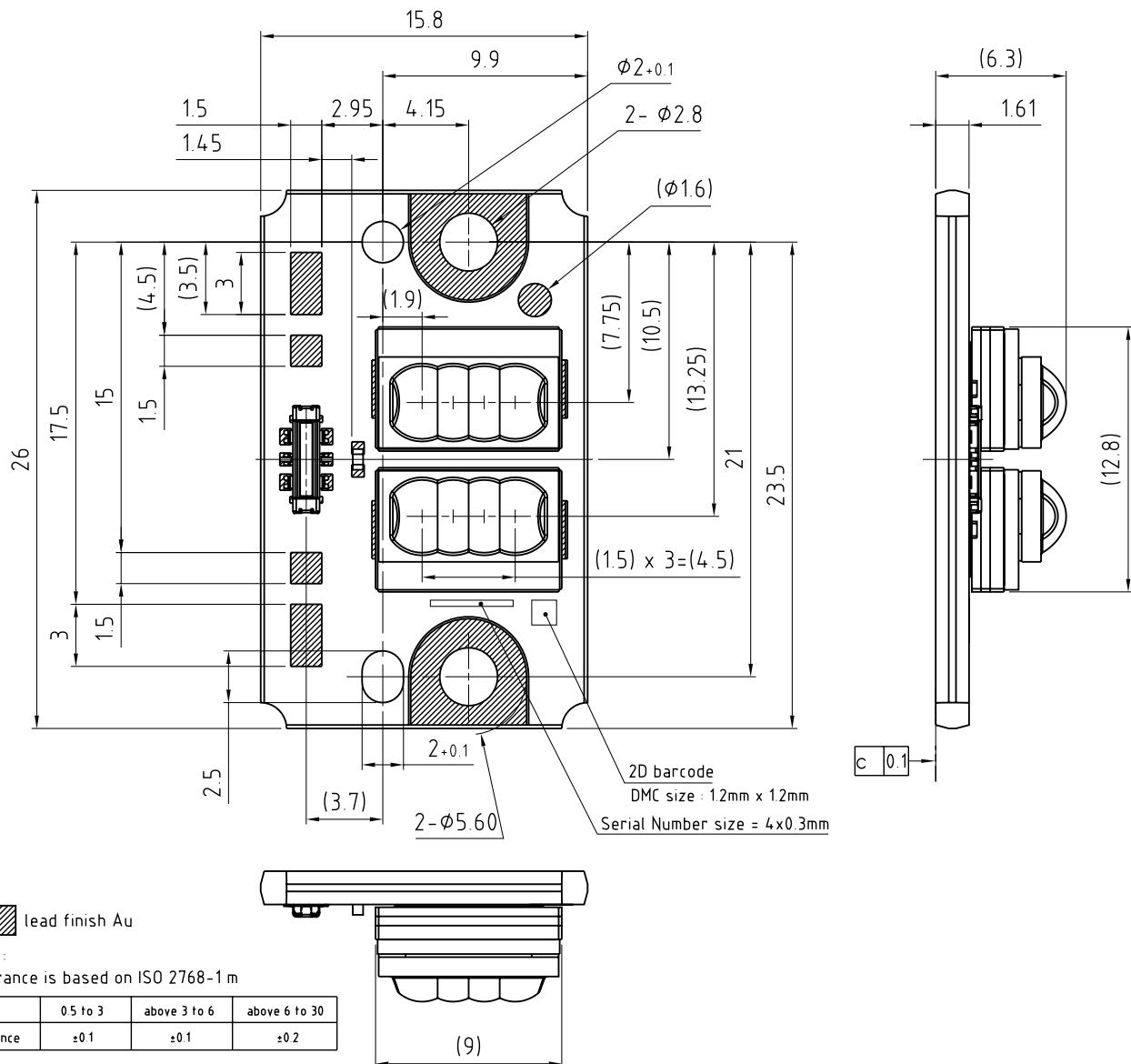


**Threshold Current** <sup>6)</sup>

$$I_{\text{th}} = f(T_{\text{op}})$$

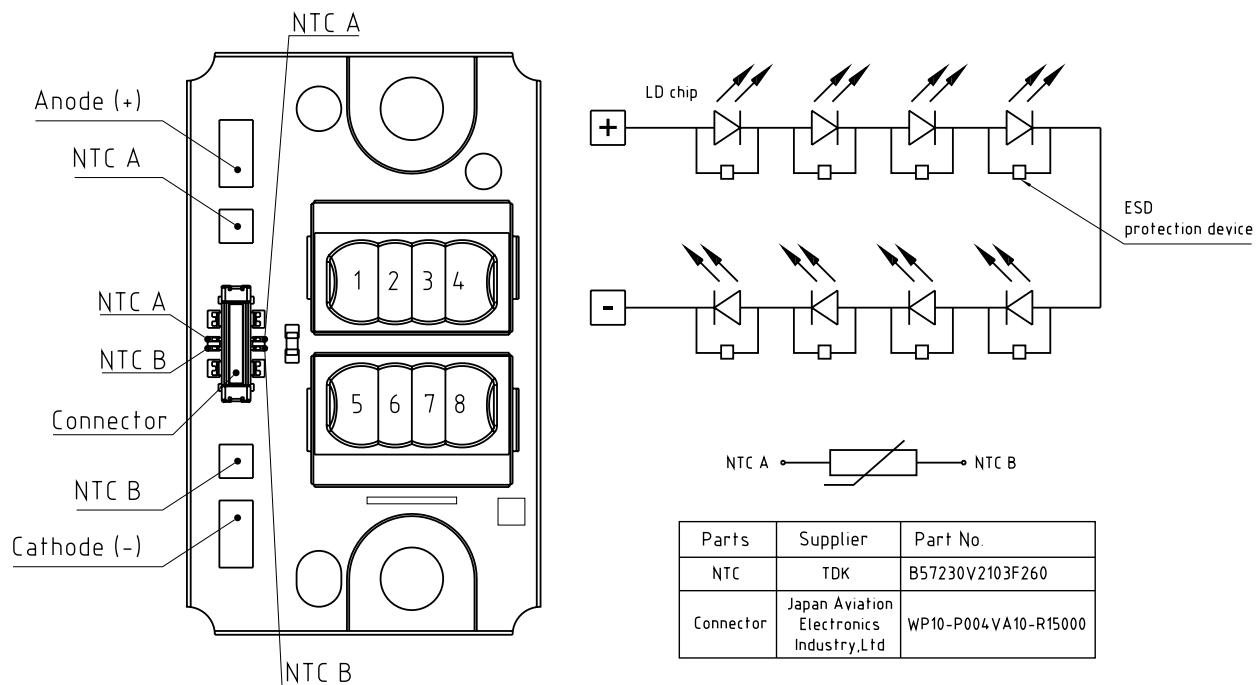


## Dimensional Drawing 8)

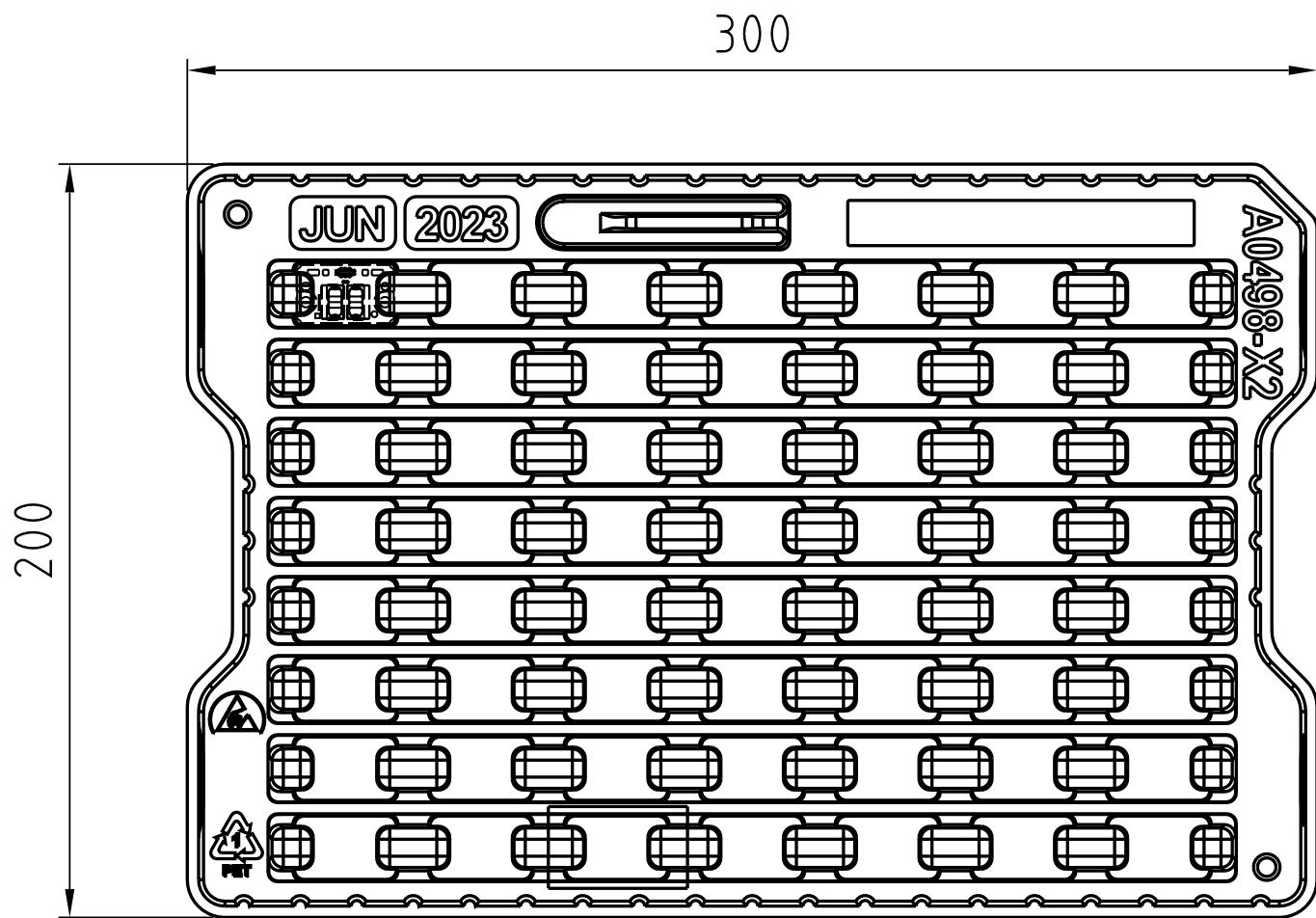


C67062-A0498-A1 -04

## Electrical Internal Circuit



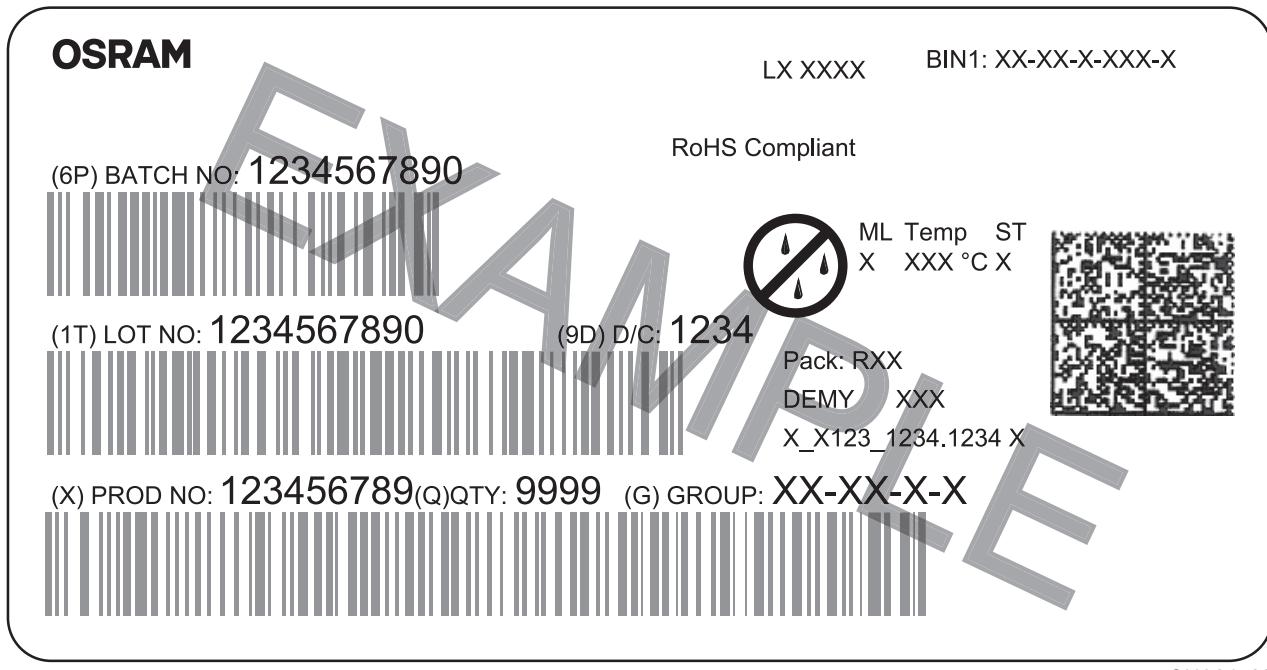
Taping <sup>8)</sup>



2x completely filled trays  
1x empty tray on top



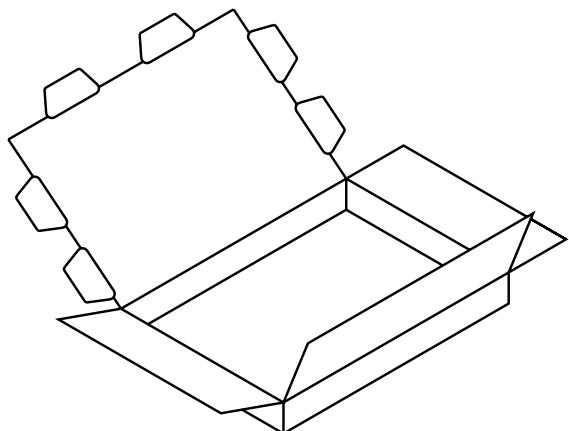
## Barcode-Product-Label (BPL)



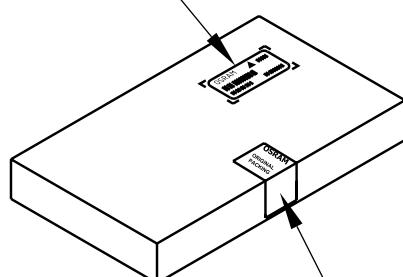
OHA04563

## Dry Packing Process and Materials

Box



Barcode label



Original packing label

## Notes

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC 60810.

The laser diode must be operated with a suitable power supply with minimized electrical noise.

The laser diode is very sensitive to electrostatic discharge (ESD). Proper precautions must be taken.

For further application related information please visit <https://ams-osram.com/support/application-notes>

Depending on the mode of operation, these devices emit highly concentrated visible light which can be Hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions found in IEC 60825-1 "Safety of laser products".



IEC 60825-1: 2014

Max radiation power: 50 W (449 - 461 nm)

## Disclaimer

### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.  
If printed or downloaded, please find the latest version on our website.

### Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

### Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.

## Glossary

- 1) **Operating temperature:** The operating temperature is defined as the temperature measured at NTC on MCPBC.
- 2) **Wavelength:** The wavelengths are measured with a tolerance of  $\pm 1$  nm.
- 3) **Brightness:** The brightness values are measured with a tolerance of  $\pm 11\%$ .
- 4) **Beam pointing tilt angle accuracy:** The values may contain measurement deviations.
- 5) **Forward Voltage:** The forward voltages are measured with a tolerance of  $\pm 0.1$  V.
- 6) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 7) **Testing temperature:** TA = 25°C (unless otherwise specified)
- 8) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with  $\pm 0.1$  and dimensions are specified in mm.

## Revision History

Version	Date	Change
1.0	2025-08-19	Initial Version
1.1	2025-08-27	Brand
1.2	2025-10-24	Features Maximum Ratings Notes



EU RoHS and China RoHS compliant product

此产品符合欧盟 RoHS 指令的要求；

按照中国的相关法规和标准，

不含有毒有害物质或元素。

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